Power transistor (-60V, -3A) 2SA2071

Features

- 1) High speed switching. (Tf: Typ.: 20ns at Ic = -3A)
- 2) Low saturation voltage, typically

(Typ.: -200mV at Ic = -2A, IB = -0.2A)

- 3) Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SC5824

Applications

Low Frequency Amplifier High speed switching

●Structure

PNP Silicon epitaxial planar transistor

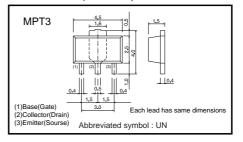
Packaging specifications

	Package	Taping
Туре	Code	T100
	Basic ordering unit (pieces)	1000
2SA2071		0

● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	-60	V
Collector-emitter voltage	Vceo	-60	V
Emitter-base voltage	Vево	-6	V
Callagtar augrent	Ic	-3	Α
Collector current	Іср	-6	A *1
Power dissipation	Pc	500	mW
Power dissipation	PC	2.0	W *2
Junction temperature	Tj	150	°C
Range of storage temperature	Tstg	-55~+150	°C

●Dimensions (Unit:mm)



^{*1} Pw=100ms *2 Mounted on a 40×40×0.7 (mm) ceramic substrate

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	-60	_	_	٧	Ic= -100μA
Collector-emitter breakdown voltage	BVceo	-60	_	_	٧	Ic=-1mA
Emitter-base breakdown voltage	ВУево	-6	_	_	٧	I _E = -100μA
Collector cut-off current	Ісво	_	_	-1.0	μΑ	V _{CB} = -40V
Emitter cut-off current	ІЕВО	_	_	-1.0	μΑ	V _{EB} = -4V
Collector-emitter saturation voltage	VCE (sat)	_	-200	-500	mV	Ic= -2A, I _B = -0.2A *1
DC current gain	hfe	120	_	390	_	Vc=-2V, Ic=-100mA
Transition frequency	f⊤	_	180	_	MHz	Vc=-10V, I=10mA, f=10MHz *1
Collector output capacitance	Cob	_	50	_	pF	Vcb=-10V, Ie=0mA, f=1MHz
Turn-on time	Ton	_	20	_	ns	Ic= -3A
Storage time	Tstg	_	150	_	ns	Ів1= –300mA Ів2=300mA
Fall time	Tf	-	20	_	ns	Vcc ≒ −25V *2

^{*1} Non repetitive pulse

●hFE RANK

Q	
120-270	

•Electrical characteristic curves

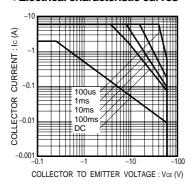


Fig.1 Safe Operating Area

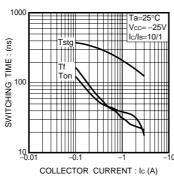


Fig.2 Switching Time

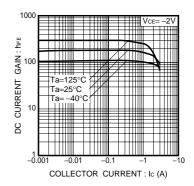


Fig.3 DC Current Gain vs. Collector Current (I)

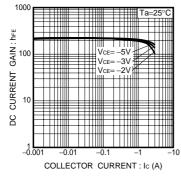


Fig.4 DC Current Gain vs. Collector Current (II)

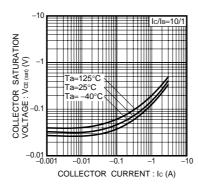


Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

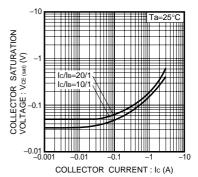


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II)

Rev.A

^{*2} See switching charactaristics measurement cicuits

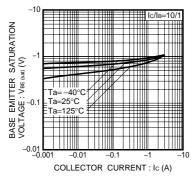


Fig.7 Base-Emitter Saturation Voltage vs. Collecter Current

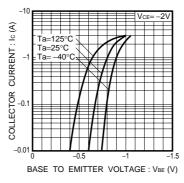


Fig.8 Grounded Emitter
Propagation Characteristics

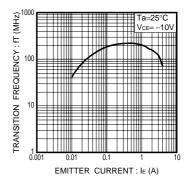


Fig.9 Transition Frequency

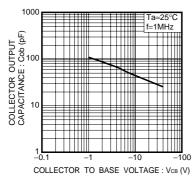
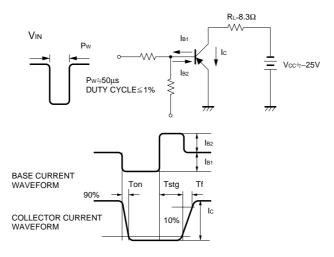


Fig.10 Collector Output Capacitance

•Switching characteristics measurement circuits



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